

N-Channel 150-V (D-S) MOSFET

Key Features:

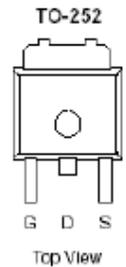
- Low $r_{DS(on)}$ trench technology
- Low thermal impedance
- Fast switching speed

Typical Applications:

- PoE Power Sourcing Equipment
- PoE Powered Devices
- Telecom DC/DC converters
- White LED boost converters



RoHS
COMPLIANT
HALOGEN
FREE



PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ (m Ω)	I_D (A)
150	255 @ $V_{GS} = 10V$	12
	290 @ $V_{GS} = 4.5V$	11

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$ UNLESS OTHERWISE NOTED)

Parameter	Symbol	Limit	Units
Drain-Source Voltage	V_{DS}	150	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current	I_D	10	A
Pulsed Drain Current ^b	I_{DM}	50	
Continuous Source Current (Diode Conduction)	I_S	45	A
Power Dissipation	P_D	50	W
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 to 175	$^\circ C$

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient ^a	$R_{\theta JA}$	50	$^\circ C/W$
Maximum Junction-to-Case	$R_{\theta JC}$	3	

Notes

- Surface Mounted on 1" x 1" FR4 Board.
- Pulse width limited by maximum junction temperature

Electrical Characteristics

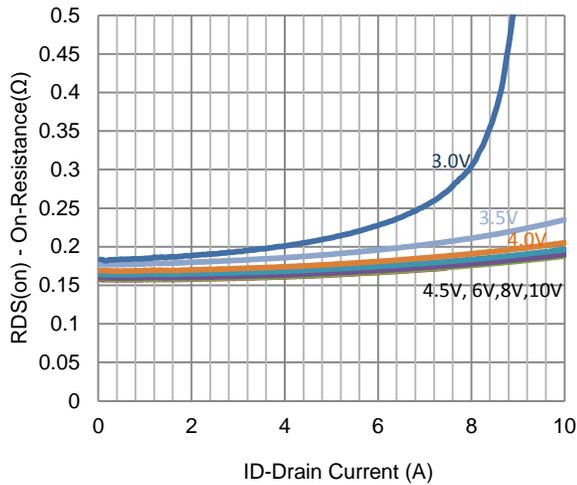
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static						
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1			V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 V, V_{GS} = 20 V$			± 10	μA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 120 V, V_{GS} = 0 V$			1	μA
		$V_{DS} = 120 V, V_{GS} = 0 V, T_J = 55^\circ C$			25	
On-State Drain Current	$I_{D(on)}$	$V_{DS} = 5 V, V_{GS} = 10 V$	34			A
Drain-Source On-Resistance	$r_{DS(on)}$	$V_{GS} = 10 V, I_D = 6 A$			255	m Ω
		$V_{GS} = 4.5 V, I_D = 5 A$			290	
Forward Transconductance	g_{fs}	$V_{DS} = 15 V, I_D = 6 A$		20		S
Diode Forward Voltage	V_{SD}	$I_S = 25 A, V_{GS} = 0 V$		0.95		V
Dynamic						
Total Gate Charge	Q_g	$V_{DS} = 75 V, V_{GS} = 4.5 V, I_D = 6 A$		16.7		nC
Gate-Source Charge	Q_{gs}			3.5		
Gate-Drain Charge	Q_{gd}			9.3		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 75 V, R_L = 12.5 \Omega, I_D = 6 A,$ $V_{GEN} = 10 V, R_{GEN} = 6 \Omega$		11		ns
Rise Time	t_r			34		
Turn-Off Delay Time	$t_{d(off)}$			46		
Fall Time	t_f			77		
Input Capacitance	C_{iss}	$V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz$		965		pF
Output Capacitance	C_{oss}			86		
Reverse Transfer Capacitance	C_{rss}			55		

Notes

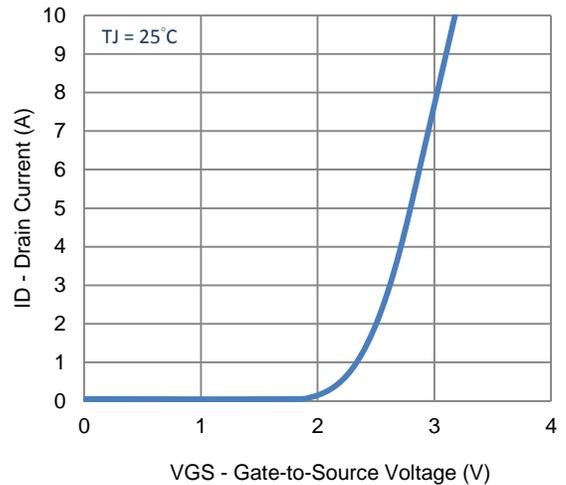
- Pulse test: $PW \leq 300 \mu s$ duty cycle $\leq 2\%$.
- Guaranteed by design, not subject to production testing.

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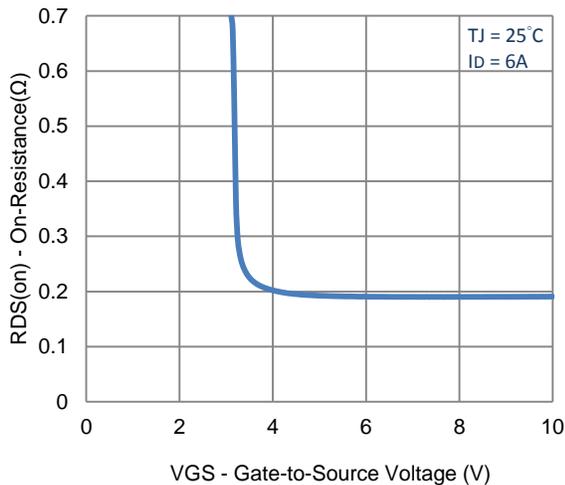
Typical Electrical Characteristics



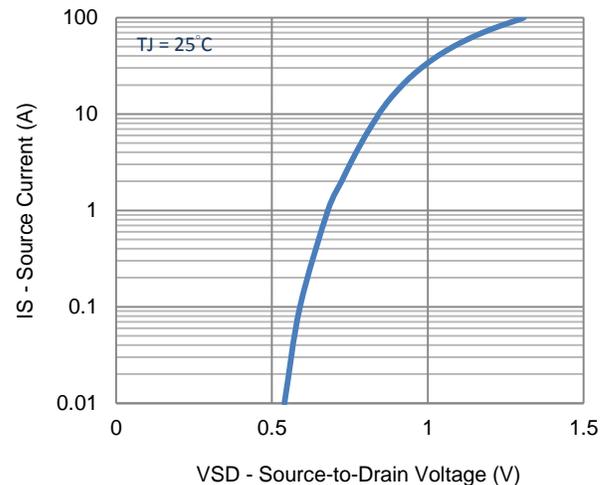
1. On-Resistance vs. Drain Current



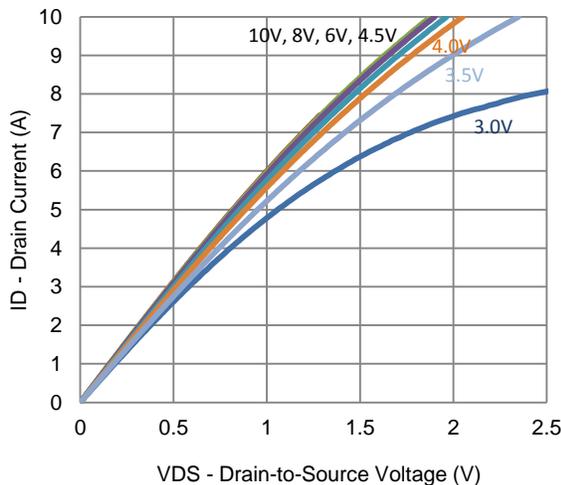
2. Transfer Characteristics



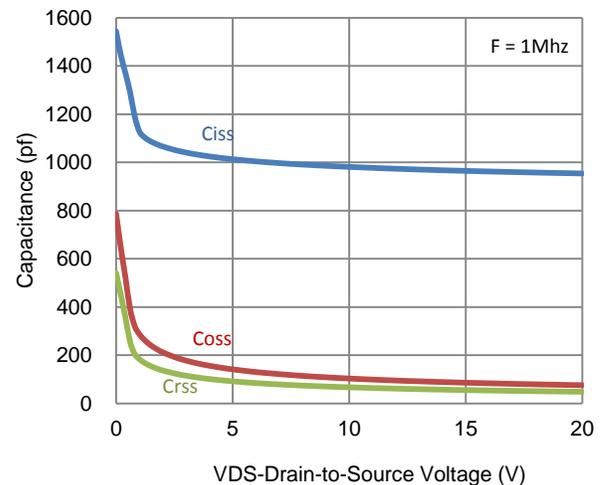
3. On-Resistance vs. Gate-to-Source Voltage



4. Drain-to-Source Forward Voltage

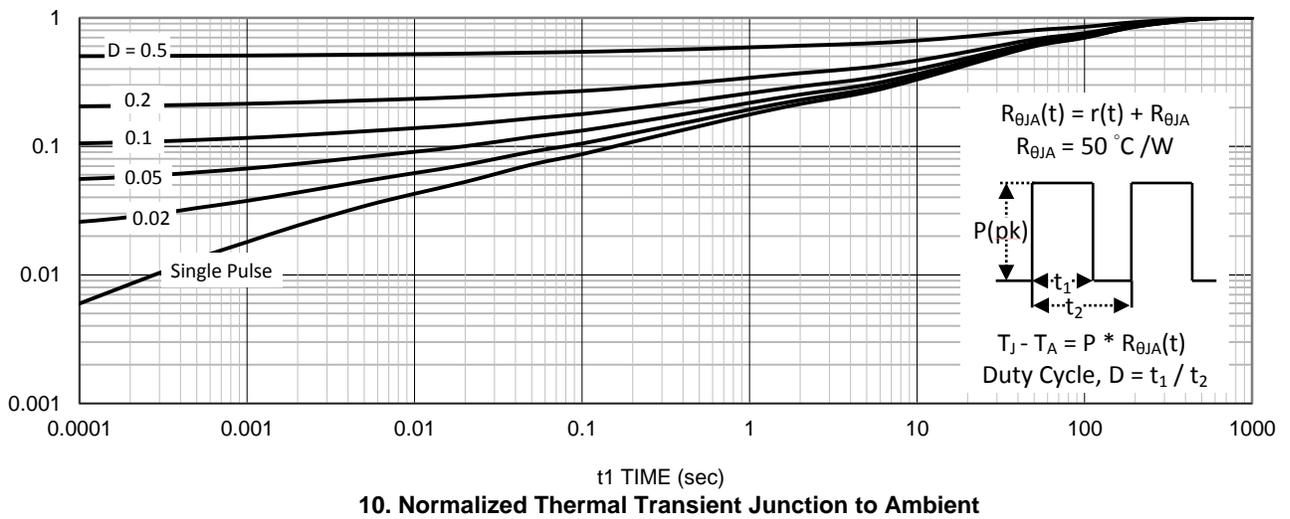
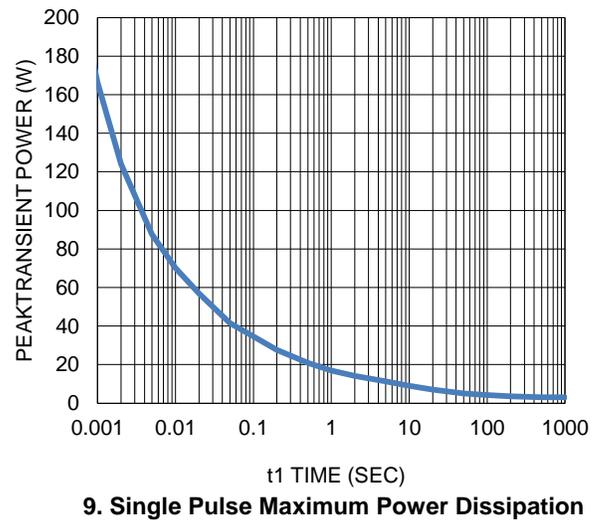
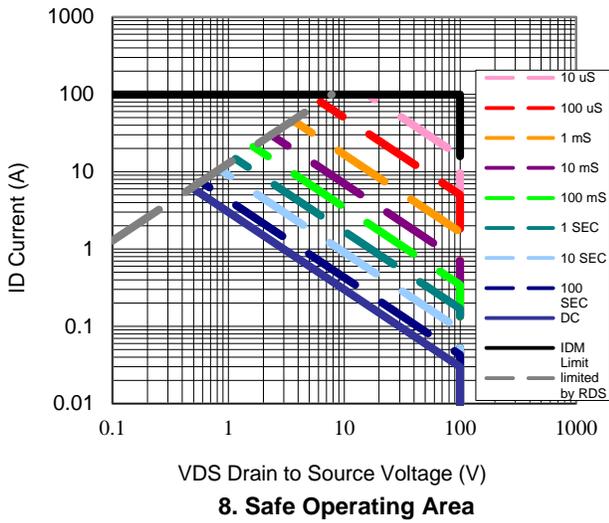
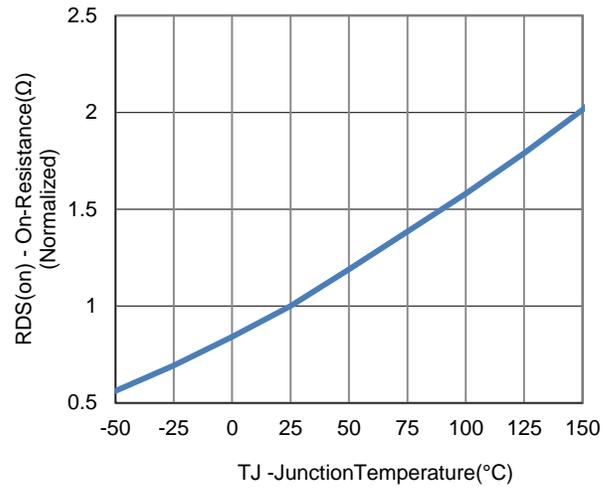
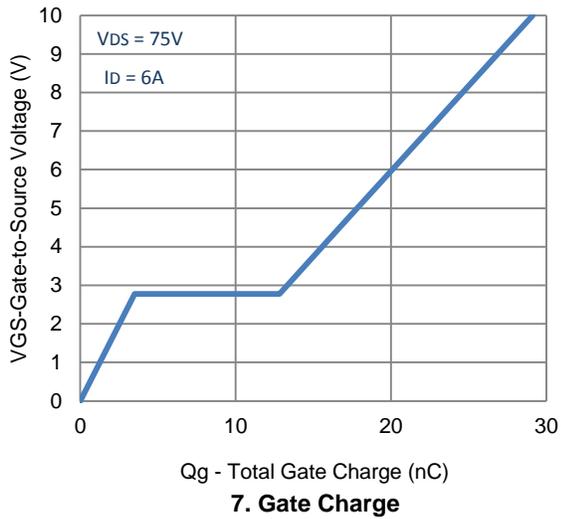


5. Output Characteristics

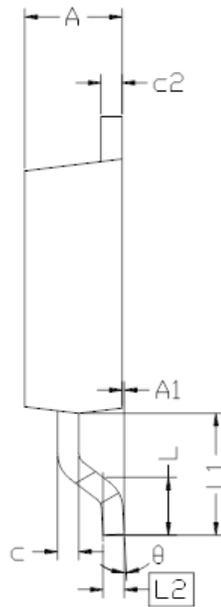
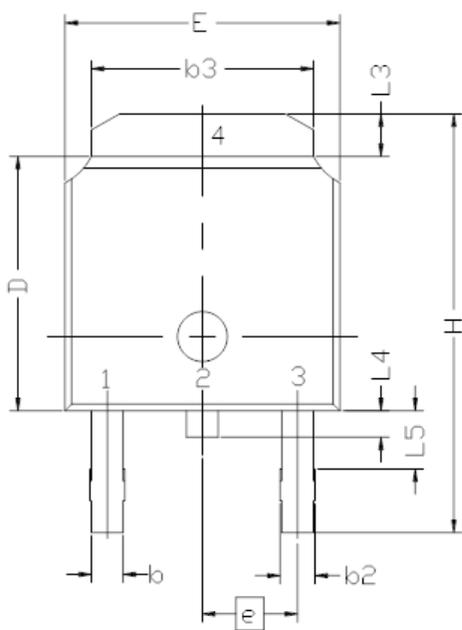


6. Capacitance

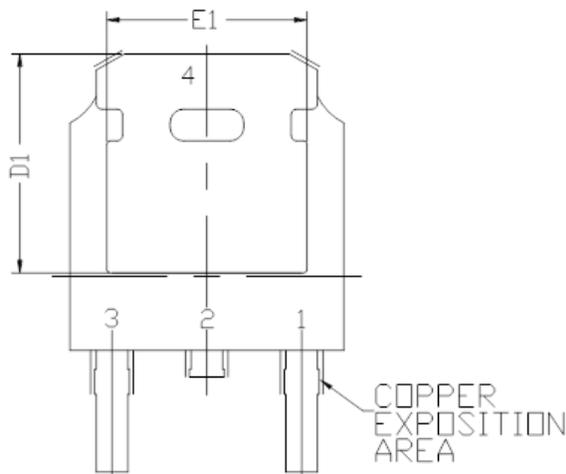
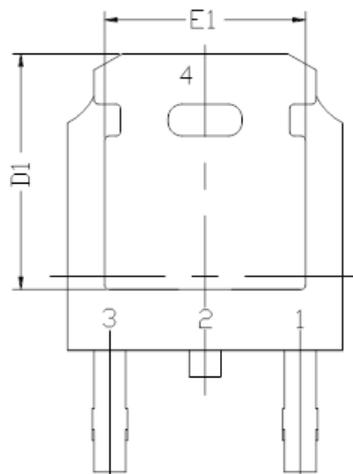
Typical Electrical Characteristics



Package Information



SYMBOL	DIMENSIONAL REQMTS		
	MIN	NOM	MAX
E	6.40	6.60	6.731
L	1.40	1.52	1.77
L1	2.743 REF		
L2	0.508 BSC		
L3	0.89	--	1.27
L4	0.64	--	1.01
L5	--	--	--
D	6.00	6.10	6.223
H	9.40	10.00	10.40
b	0.64	0.76	0.88
b2	0.77	0.84	1.14
b3	5.21	5.34	5.46
e	2.286 BSC		
A	2.20	2.30	2.38
A1	0	--	0.127
c	0.45	0.50	0.60
c2	0.45	0.50	0.58
D1	5.30	--	--
E1	4.40	--	--
θ	0°	--	10°



Note:

1. All Dimension Are In mm.
2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.

Ordering Information

- **AM20N15-250D-T1-XX**
 - A: Analog Power
 - M: MOSFET
 - 20N15-250: Part number, N-Channel
 - D: TO-252
 - T1: Tape & reel
 - XX: Blank: Standard
PF: Leadfree